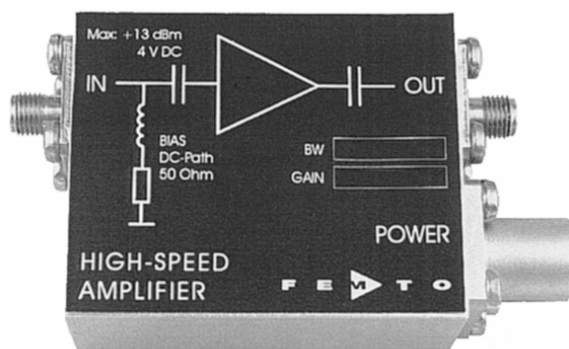
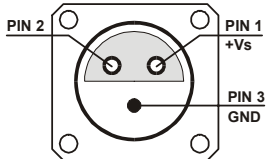
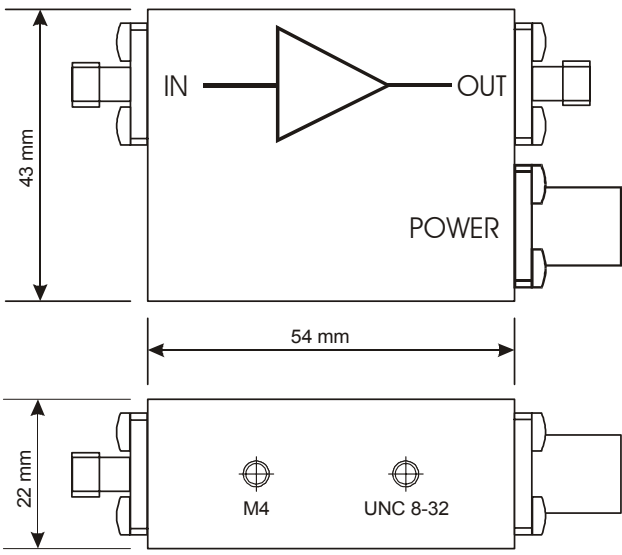


## 2 GHz High-Speed Amplifier



<p>Features</p>	<ul style="list-style-type: none"> <li>• <b>Bandwidth 10 kHz ... 2 GHz</b></li> <li>• <b>Rise Time 180 ps</b></li> <li>• <b>Gain 20 dB</b></li> <li>• <b>Input VSWR 1 : 1.1</b></li> <li>• <b>Integrated Bias Circuit</b></li> </ul>																																						
<p>Applications</p>	<ul style="list-style-type: none"> <li>• <b>Preamplifier for ultra-fast Detectors (Microchannel-Plates, Photomultipliers, Avalanche-Photodiodes and PIN-Photodiodes)</b></li> <li>• <b>Oscilloscope and Transient-Recorder Preamplifier</b></li> <li>• <b>Time-Resolved Pulse and Transient Measurements</b></li> </ul>																																						
<p>Block Diagram</p>																																							
<p>Specifications</p>	<table border="0"> <tr> <td></td> <td><i>Test Conditions</i></td> <td><i>Vs = + 15 V, Ta = 25°C, System Impedance = 50 Ω</i></td> </tr> <tr> <td rowspan="3">Gain</td> <td>Gain</td> <td>20 dB</td> </tr> <tr> <td>Gain Accuracy</td> <td>± 1 dB</td> </tr> <tr> <td>Gain Flatness (overall)</td> <td>± 0.2 dB</td> </tr> <tr> <td rowspan="2">Frequency Response</td> <td>Lower Cut-Off Frequency</td> <td>10 kHz</td> </tr> <tr> <td>Upper Cut-Off Frequency</td> <td>2 GHz</td> </tr> <tr> <td>Time Response</td> <td>Rise / Fall Time (10% - 90%)</td> <td>180 ps</td> </tr> <tr> <td rowspan="6">Input</td> <td>DC Input Impedance</td> <td>50 Ω</td> </tr> <tr> <td>RF Input Impedance</td> <td>50 Ω</td> </tr> <tr> <td>50 Ω Noise Figure</td> <td>4.9 dB (@ f &lt; 1 GHz)</td> </tr> <tr> <td>Equivalent Input Voltage Noise</td> <td>650 pV/√Hz (@ f &lt; 1 GHz)</td> </tr> <tr> <td>Input VSWR</td> <td>1 : 1.1 (@ f &lt; 1 GHz)</td> </tr> <tr> <td>Maximum Input VSWR</td> <td>1 : 1.2 (@ f &lt; 3 GHz)</td> </tr> <tr> <td rowspan="3">Output</td> <td>Output Impedance</td> <td>50 Ω</td> </tr> <tr> <td>Output Power P<sub>1dB</sub></td> <td>+ 11.5 dBm (@ f &lt; 1 GHz)</td> </tr> <tr> <td>Output Peak-Peak Voltage</td> <td>1.9 Vpp (@ f &lt; 500 MHz, for linear Amplification)</td> </tr> </table>		<i>Test Conditions</i>	<i>Vs = + 15 V, Ta = 25°C, System Impedance = 50 Ω</i>	Gain	Gain	20 dB	Gain Accuracy	± 1 dB	Gain Flatness (overall)	± 0.2 dB	Frequency Response	Lower Cut-Off Frequency	10 kHz	Upper Cut-Off Frequency	2 GHz	Time Response	Rise / Fall Time (10% - 90%)	180 ps	Input	DC Input Impedance	50 Ω	RF Input Impedance	50 Ω	50 Ω Noise Figure	4.9 dB (@ f < 1 GHz)	Equivalent Input Voltage Noise	650 pV/√Hz (@ f < 1 GHz)	Input VSWR	1 : 1.1 (@ f < 1 GHz)	Maximum Input VSWR	1 : 1.2 (@ f < 3 GHz)	Output	Output Impedance	50 Ω	Output Power P <sub>1dB</sub>	+ 11.5 dBm (@ f < 1 GHz)	Output Peak-Peak Voltage	1.9 Vpp (@ f < 500 MHz, for linear Amplification)
	<i>Test Conditions</i>	<i>Vs = + 15 V, Ta = 25°C, System Impedance = 50 Ω</i>																																					
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## 2 GHz High-Speed Amplifier

Power Supply	Supply Voltage Supply Current	+ 15 V + 85 mA
Case	Weight Material	100 gr. (0.23 lbs) AlMg4.5Mn, nickel-plated
Temperature Range	Storage Temperature Operating Ambient Temperature Operating Case Temperature	- 40 ... + 100 °C 0 ... + 60 °C 35 °C
Absolute Maximum Ratings	Power Supply Voltage DC and LF Input Voltage RF Input Power	+ 20 V ± 4 V + 13 dBm
Connectors	Input Output Power Supply	SMA SMA LEMO Series 1S, 3-pin fixed Socket Pin 1: + 15 V Pin 2: n.c. Pin 3: GND
		
Dimensions	 <p style="text-align: right;">DZ01-0601-10</p>	

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